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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/139,935	08/25/1998	FWU-IUAN HSHIEH	2154-11	5942
7.	590 01/14/2005		EXAMINER	
KAM T TAM 3077 PAVAN DRIVE			NADAV, ORI	
SAN JOSE, C.			ART UNIT	PAPER NUMBER
·			2811	
			DATE MAILED: 01/14/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

			AU				
	Application No.	Applicant(s)					
	09/139,935	HSHIEH, FWU-IUAI	N				
Office Action Summary	Examiner	Art Unit					
• ,	ori nadav	2811					
The MAILING DATE of this communication app Period for Reply	ears on the cover she	et with the correspondence add	ress				
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply - If NO period for reply is specified above, the maximum statutory period w - Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, m within the statutory minimum will apply and will expire SIX (6) cause the application to beco	ray a reply be timely filed of thirty (30) days will be considered timely. MONTHS from the mailing date of this comme ABANDONED (35 U.S.C. § 133).	nmunication.				
Status							
1) Responsive to communication(s) filed on 20 A	oril 2004.						
2a)⊠ This action is FINAL . 2b)□ This	action is non-final.						
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is							
closed in accordance with the practice under E	x parte Quayle, 1935	C.D. 11, 453 O.G. 213.					
Disposition of Claims							
4) Claim(s) 1-19 and 21-33 is/are pending in the a							
5)⊠ Claim(s) <u>32 and 33</u> is/are allowed.		•					
6)⊠ Claim(s) <u>1-19 and 21-31</u> is/are rejected.							
7) Claim(s) is/are objected to.							
8) Claim(s) are subject to restriction and/o	r election requirement	l.					
Application Papers							
9) The specification is objected to by the Examine	r.						
10)⊠ The drawing(s) filed on <u>20 April 2004</u> is/are: a)⊠ accepted or b)⊡ objected to by the Examiner.							
Applicant may not request that any objection to the	Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).						
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).							
11)☐ The oath or declaration is objected to by the Ex	caminer. Note the atta	ched Office Action or form PTC	D-152 .				
Priority under 35 U.S.C. § 119							
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of:							
1. Certified copies of the priority documents have been received.							
2. Certified copies of the priority documents have been received in Application No							
3. Copies of the certified copies of the priority documents have been received in this National Stage							
application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received.							
The attached detailed office detail for a fiel of the continue copies not received.							
Attachment(s) 1) Notice of References Cited (PTO-892)	∆ ☐ Inten	view Summary (PTO-413)					
2) Notice of Pro-948) Notice of Draftsperson's Patent Drawing Review (PTO-948)	Pape	er No(s)/Mail Date					
Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date	5)	ce of Informal Patent Application (PTO- r:	-152)				
I.S. Patent and Trademark Office		···					

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DETAILED ACTION

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1-19 and 21-31 are rejected under 35 U.S.C. 103(a) as being unpatentable over Matsuda et al. (5,770,514).

Matsuda et al. teach in figure 3 and related text the entire claimed structure including a semiconductor structure comprising: a substrate 11 having a major surface,

at least one trench in the substrate includes inner surfaces filled with conductive material 17 comprising polysilicon, electrically separated from the substrate by insulating material 16,

a first insulating layer disposed on the major surface above the trench and having a first contact opening,

a first conductive layer 24 comprising aluminum disposed above the first insulating layer and in contact with the conductive material in the trench through the first contact opening, said first conductive layer having conductivity higher than the conductivity of said conductive material;

a second insulating layer 25 disposed above the first conductive layer and having a second contact opening, and

a second conductive layer 23 disposed in the second insulating layer 25 and in contact with the substrate through the second contact opening,

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a source layer, a drain and a gate includes the trench.

Matsuda et al. do not teach a second conductive layer disposed above the second insulating layer. It would have been obvious to a person of ordinary skill in the art at the time the invention was made to form a second conductive layer above the second insulating layer in order to operate the device by providing external connections to the device. Note that the device would not operate without external connections.

Regarding claims 4, 24 and 30, Matsuda et al. teach second conductive layer being substantially rectangular in shape and having no elongated voids extended therein.

Regarding claims 5, 6, 25 and 29, Matsuda et al. teach a first insulating layer comprising silicon dioxide. It would have been obvious to a person of ordinary skill in the art at the time the invention was made to form a second insulating layer comprising BPSG in Matsuda et al.'s device in order to provide better protection for the device.

Regarding claims 7-12, 19, 22, 23, 26, 29 and 31, Matsuda et al. teach a conductive layer comprising metal and a gate material inside the trench comprising polysilicon.

Regarding claim 14, Matsuda et al. teach a trench being a elongated in shape.

Claims 15-19 and 21-31 are rejected under 35 U.S.C. 103(a) as being unpatentable over Matsuda et al. in view of Blanchard (5,034,785).

Matsuda et al. teach substantially the entire claimed structure, as applied to claim 1 above, except stating that the trenches are formed in first and second directions.

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Blanchard teaches in figure 9 trenches formed in first and second directions. It would have been obvious to a person of ordinary skill in the art at the time the invention was made to form trenches in first and second directions in Matsuda et al.'s device, because the layout of a circuit is a matter of design choice within ordinary skill in the art, subject to routine experimentation and optimization to find the most efficient layout for the circuit.

Allowable Subject Matter

Claims 32 and 33 are allowable.

Response to Arguments

Applicant's arguments with respect to claims 1-19 and 21-31 have been considered but are most in view of the new ground(s) of rejection.

Conclusion

Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within

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TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Papers related to this application may be submitted to Technology center (TC) 2800 by facsimile transmission. Papers should be faxed to TC 2800 via the TC 2800 Fax center located in Crystal Plaza 4, room 4-C23. The faxing of such papers must conform with the notice published in the Official Gazette, 1096 OG 30 (November 15, 1989). The Group 2811 Fax Center number is (703) 308-7722 and 308-7724. The Group 2811 Fax Center is to be used only for papers related to Group 2811 applications.

Any inquiry concerning this communication or any earlier communication from the Examiner should be directed to *Examiner Nadav* whose telephone number is **(571) 272-1660**. The Examiner is in the Office generally between the hours of 7 AM to 4 PM (Eastern Standard Time) Monday through Friday.

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Any inquiry of a general nature or relating to the status of this application should be directed to the **Technology Center Receptionists** whose telephone number is **308-0956**

O.N. 1/11/05 ORI NADAV PRIMARY EXAMINER TECHNOLOGY CENTER 2800